

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74HC240AP,TC74HC240AF,TC74HC240AFW TC74HC241AP,TC74HC241AF TC74HC244AP,TC74HC244AF,TC74HC244AFW

### Octal Bus Buffer

TC74HC240AP/AF/AFW	Inverted, 3-State Outputs
TC74HC241AP/AF	Non-Inverted, 3-State Outputs
TC74HC244AP/AF/AFW	Non-Inverted, 3-State Outputs

The TC74HC240A, 241A and 244A are high speed CMOS OCTAL BUS BUFFERS fabricated with silicon gate CMOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC240A is an inverting 3-state buffer having two active-low output enables. The TC74HC241A and TC74HC244A are non-inverting 3-state buffers that differ only in that the 241A has one active-high and one active-low output enable, and the 244A has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

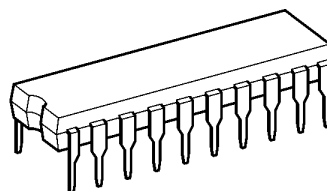
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### Features

- High speed:  $t_{pd} = 10 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu\text{A}$  (max) at  $T_a = 25^\circ\text{C}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 6 \text{ mA}$  (min)
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC} \text{ (opr)} = 2\sim 6 \text{ V}$
- Pin and function compatible with 74LS240/241/244

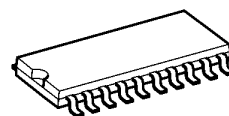
Note: xxxFW (JEDEC SOP) is not available in Japan.

TC74HC240AP, TC74HC241AP,  
TC74HC244AP

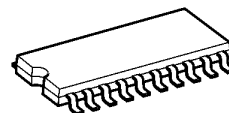


DIP20-P-300-2.54A

TC74HC240AF, TC74HC241AF, TC74HC244AF

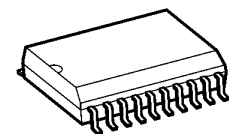


SOP20-P-300-1.27A



SOP20-P-300-1.27

TC74HC240AFW, TC74HC244AFW



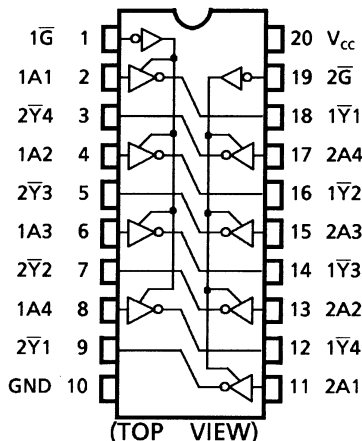
SOL20-P-300-1.27

### Weight

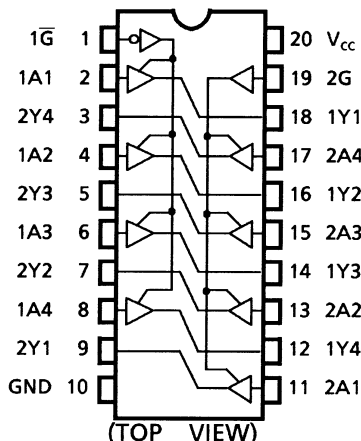
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)

## Pin Assignment

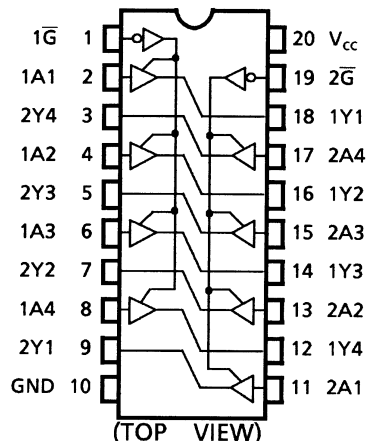
**TC74HC240A**



**TC74HC241A**

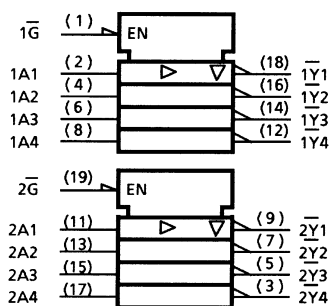


**TC74HC244A**

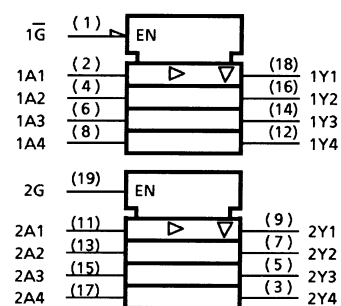


## IEC Logic Symbol

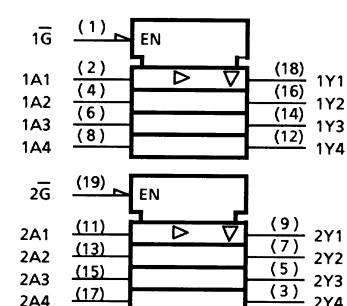
**TC74HC240A**



**TC74HC241A**



**TC74HC244A**



## Truth Table

Inputs			Outputs	
$\overline{G}$	$G^{\Delta}$	$A_n$	$Y_n$	$\overline{Y}_n^{\Delta\Delta}$
L	H	L	L	H
L	H	H	H	L
H	L	X	Z	Z

$\Delta$ : For TC74HC241A only

$\Delta\Delta$ : For TC74HC240A only

X: Don't care

Z: High impedance

**Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5~7	V
DC input voltage	$V_{IN}$	-0.5~ $V_{CC} + 0.5$	V
DC output voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$	$\pm 20$	mA
Output diode current	$I_{OK}$	$\pm 20$	mA
DC output current	$I_{OUT}$	$\pm 35$	mA
DC $V_{CC}$ /ground current	$I_{CC}$	$\pm 75$	mA
Power dissipation	$P_D$	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	$T_{stg}$	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of  $T_a = -40$  to  $65^\circ\text{C}$ . From  $T_a = 65$  to  $85^\circ\text{C}$  a derating factor of  $-10 \text{ mW}/^\circ\text{C}$  shall be applied until 300 mW.

**Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	2~6	V
Input voltage	$V_{IN}$	0~ $V_{CC}$	V
Output voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating temperature	$T_{opr}$	-40~85	°C
Input rise and fall time	$t_r, t_f$	0~1000 ( $V_{CC} = 2.0 \text{ V}$ ) 0~500 ( $V_{CC} = 4.5 \text{ V}$ ) 0~400 ( $V_{CC} = 6.0 \text{ V}$ )	ns

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

**Electrical Characteristics**
**DC Characteristics**

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Ta = 25°C			Ta = −40–85°C		Unit
					Min	Typ.	Max	Min	Max	
High-level input voltage	V <sub>IH</sub>	—		2.0 4.5 6.0	1.50 3.15 4.20	— — —	— — —	1.50 3.15 4.20	— — —	V
Low-level input voltage	V <sub>IL</sub>	—		2.0 4.5 6.0	— — —	— — —	0.50 1.35 1.80	— — —	0.50 1.35 1.80	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = −20 μA	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
			I <sub>OH</sub> = −6 mA I <sub>OH</sub> = −7.8 mA	4.5	4.18	4.31	—	4.13	—	
				6.0	5.68	5.80	—	5.63	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	2.0	—	0.0	0.1	—	0.1	V
				4.5	—	0.0	0.1	—	0.1	
			I <sub>OL</sub> = 6 mA I <sub>OL</sub> = 7.8 mA	4.5	—	0.17	0.26	—	0.33	
				6.0	—	0.18	0.26	—	0.33	
3-state output off-state current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		6.0	—	—	±0.5	—	±5.0	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	—	—	4.0	—	40.0	μA

## AC Characteristics (input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40~85°C		Unit	
			CL (pF)	V <sub>CC</sub> (V)	Min	Typ.	Max	Min	Max		
Output transition time	t <sub>TLH</sub>	—	50	2.0	—	25	60	—	75	ns	
				4.5	—	7	12	—	15		
	t <sub>THL</sub>			6.0	—	6	10	—	13		
Propagation delay time	t <sub>pLH</sub> t <sub>pHL</sub>	—	50	2.0	—	36	90	—	115	ns	
					4.5	—	12	18	—		23
					6.0	—	10	15	—		20
			150	2.0	—	51	130	—	165		
					4.5	—	17	26	—		33
					6.0	—	14	22	—		28
Output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	R <sub>L</sub> = 1 kΩ	50	2.0	—	48	125	—	155	ns	
					4.5	—	16	25	—		31
					6.0	—	14	21	—		26
			150	2.0	—	63	165	—	205		
					4.5	—	21	33	—		41
					6.0	—	18	28	—		35
Output disable time	t <sub>pLZ</sub> t <sub>pHZ</sub>	R <sub>L</sub> = 1 kΩ	50	2.0	—	32	125	—	155	ns	
					4.5	—	15	25	—		31
					6.0	—	14	21	—		26
Input capacitance	C <sub>IN</sub>	—			—	5	10	—	10	pF	
Output capacitance	C <sub>OUT</sub>	—			—	10	—	—	—	pF	
Power dissipation capacitance	C <sub>PD</sub> (Note)	TC74HC240A			—	31	—	—	—	pF	
		TC74HC241A/244A			—	33	—	—	—		

Note:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

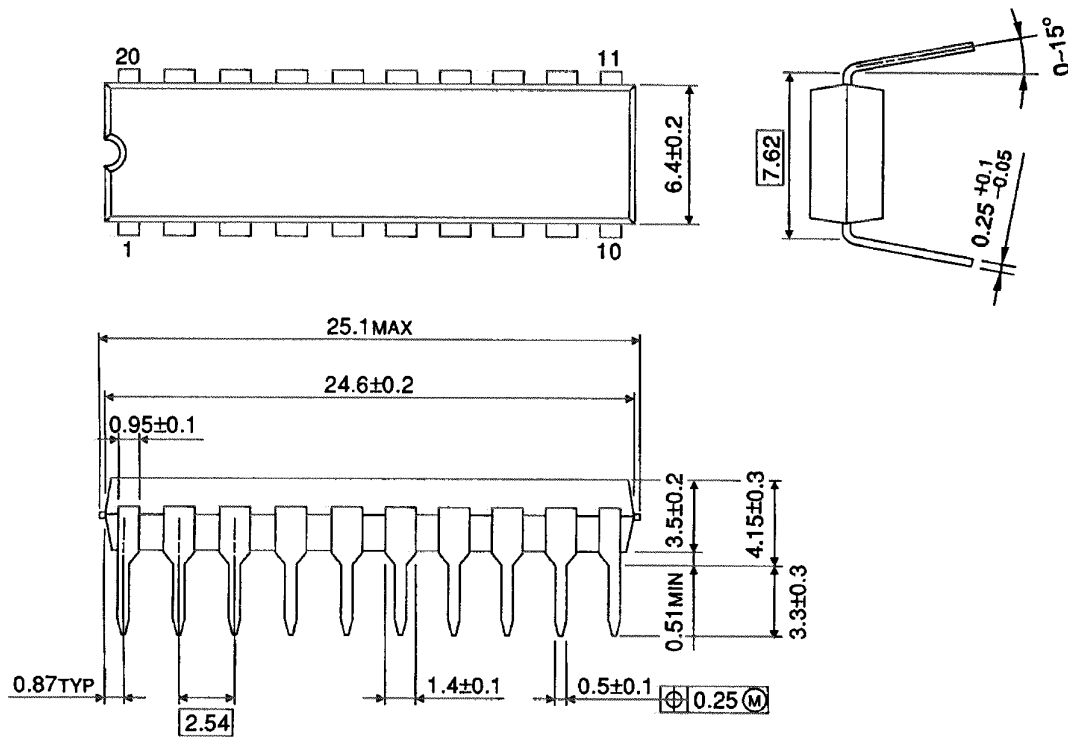
Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

## Package Dimensions

DIP20-P-300-2.54A

Unit : mm

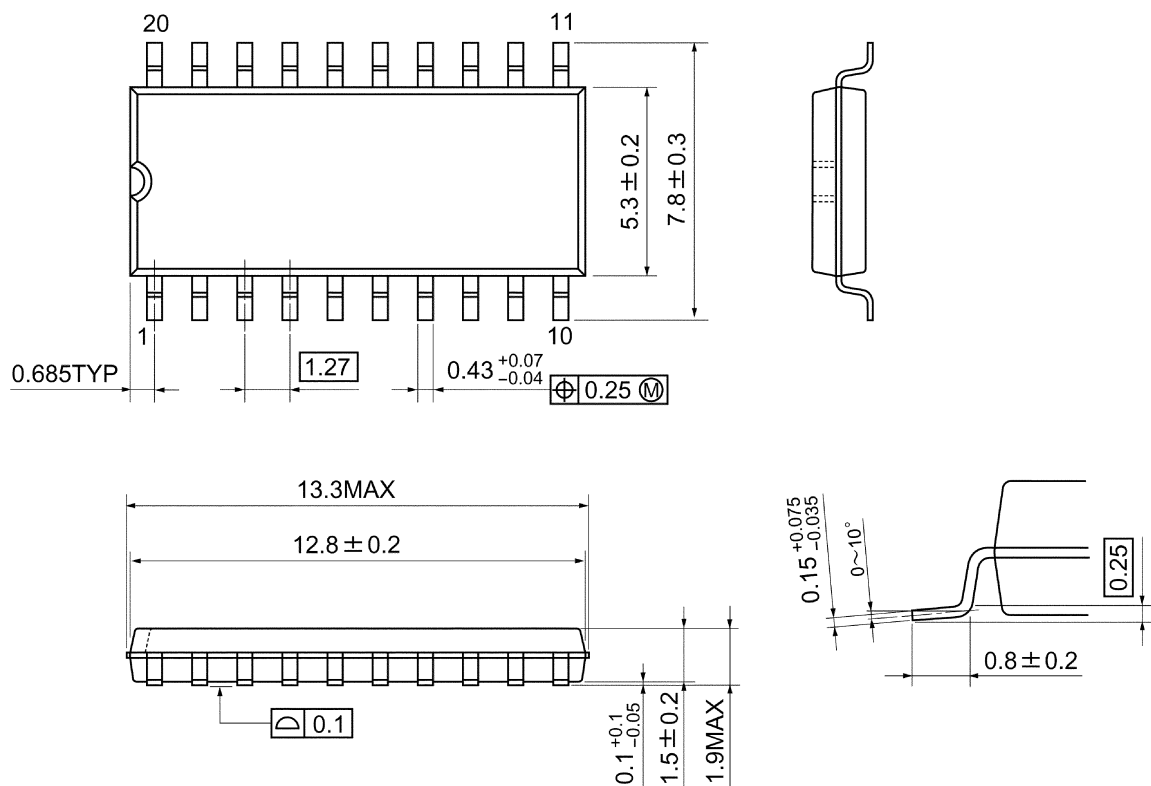


Weight: 1.30 g (typ.)

## Package Dimensions

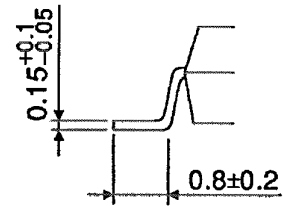
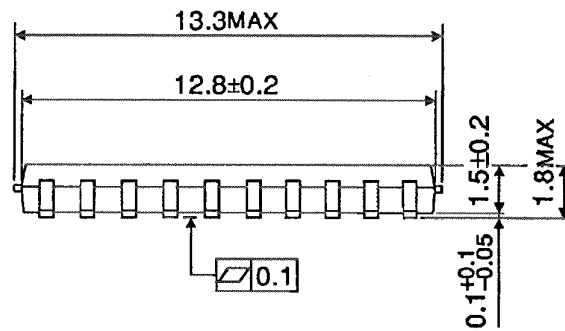
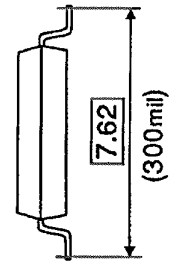
SOP20-P-300-1.27A

Unit: mm



Weight: 0.22 g (typ.)

**SOP20-P-300-1.27**



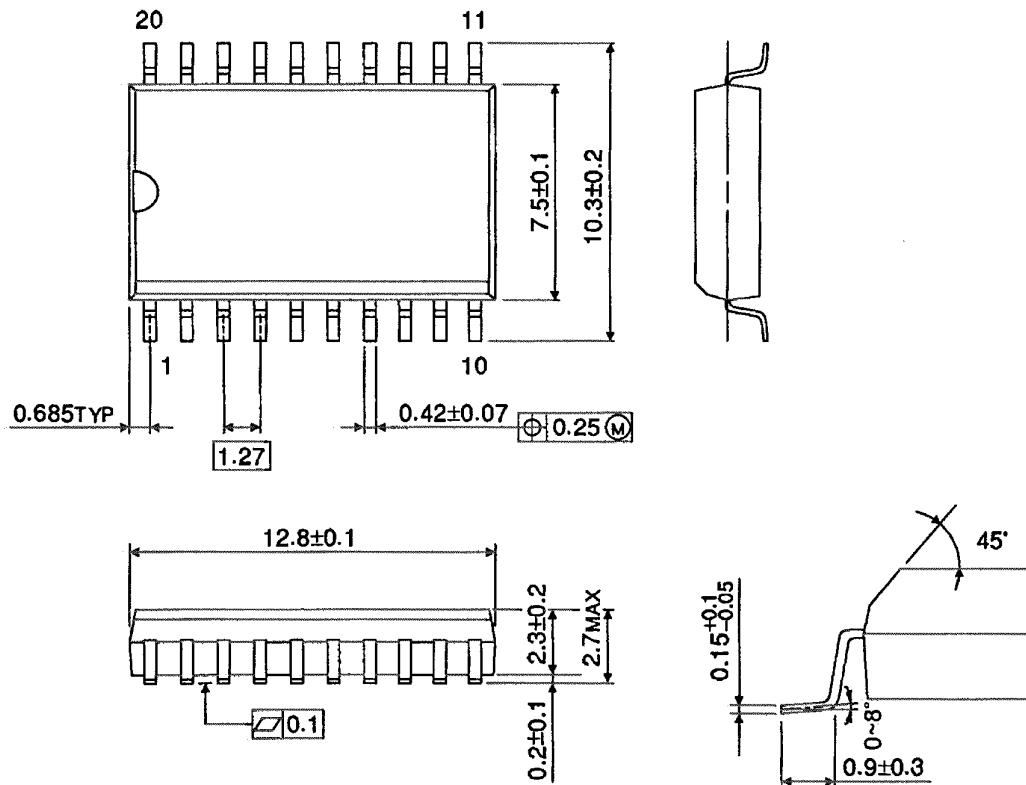
2006-02-01



## Package Dimensions (Note)

SOL20-P-300-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

**Note: Lead (Pb)-Free Packages**

**DIP20-P-300-2.54A SOP20-P-300-1.27A**

## RESTRICTIONS ON PRODUCT USE

060116EBA

- The information contained herein is subject to change without notice. 021023\_D
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.  
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc. 021023\_A
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk. 021023\_B
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations. 060106\_Q
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others. 021023\_C
- The products described in this document are subject to the foreign exchange and foreign trade laws. 021023\_E